

Features

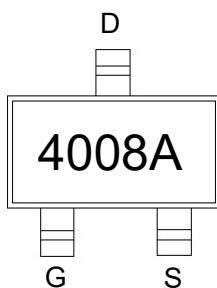
- Trench Power LV MOSFET technology
- High Density Cell Design for Low $R_{DS(ON)}$
- High Speed switching

Product Summary

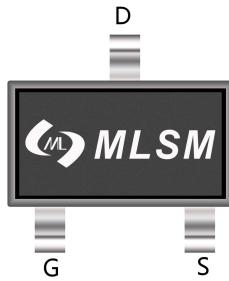
| V_{DS} | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| 40V | 16mΩ@10V | 8A |
| | 25mΩ@4.5V | |

Application

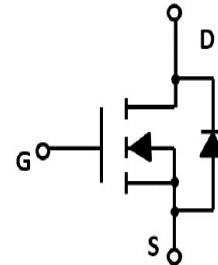
- CoBattery protection
- Load switch
- Power management



4008A: Device code



SOT-23-3L top view



Schematic diagram

Marking and pin assignment



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

Common Ratings (TC=25°C Unless Otherwise Noted)

| | | | |
|-----------|----------------------------------|------------|----|
| V_{DS} | Drain-Source Breakdown Voltage | 40 | V |
| V_{GS} | Gate-Source Voltage | ±20 | V |
| T_J | Maximum Junction Temperature | 150 | °C |
| T_{STG} | Storage Temperature Range | -50 to 155 | °C |
| I_S | Diode Continuous Forward Current | 8 | A |

Mounted on Large Heat Sink

| | | | | |
|-----------|-------------------------------------|---------|-----|------|
| I_{DM} | Pulse Drain Current Tested | Tc=25°C | 28 | A |
| I_D | Continuous Drain Current | Tc=25°C | 8 | A |
| P_D | Maximum Power Dissipation | Tc=25°C | 1.2 | W |
| $R_{θJA}$ | Thermal Resistance Junction-Ambient | | 108 | °C/W |

Ordering Information (Example)

| Type | Package | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|-----------|---------|----------------------|-------------------------|----------------------------|---------------|
| MLSK4008A | SOT-23-3L | 4008A | 3,000 | 45,000 | 180,000 | 7" reel |

Electrical Characteristics (T_J=25°C unless otherwise noted)

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
|---|----------------------------------|--|-----|-----|------|------|
| Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated) | | | | | | |
| BV _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250μA | 40 | -- | -- | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =40V, V _{GS} =0V | -- | -- | 1 | μA |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} =±20V, V _{DS} =0V | -- | -- | ±100 | nA |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250μA | 1.0 | 1.5 | 2.5 | V |
| R _{DS(on)} | Drain-Source On-State Resistance | V _{GS} =10V, I _D =8A | -- | 12 | 16 | mΩ |
| | | V _{GS} =4.5V, I _D =4A | -- | 20 | 25 | mΩ |

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

| | | | | | | |
|------------------|------------------------------|---|----|-----|----|----|
| C _{ISS} | Input Capacitance | V _{DS} =20V, V _{GS} =0V, f=1MHz | -- | 965 | -- | pF |
| C _{OSS} | Output Capacitance | | -- | 110 | -- | pF |
| C _{RSS} | Reverse Transfer Capacitance | | -- | 95 | -- | pF |

Switching Characteristics

| | | | | | | |
|---------------------|---------------------|---|----|-----|----|----|
| Q _g | Total Gate Charge | V _{DS} =10V, I _D =3A, V _{GS} =20V | -- | 22 | -- | nC |
| Q _{gs} | Gate Source Charge | | -- | 3.5 | -- | nC |
| Q _{gd} | Gate Drain Charge | | -- | 5.3 | -- | nC |
| t _{d(on)} | Turn-on Delay Time | V _{DS} =20V, I _D =8A, V _{GS} =10V, R _G =3Ω | -- | 5.5 | -- | nS |
| t _r | Turn-on Rise Time | | -- | 14 | -- | nS |
| t _{d(off)} | Turn-Off Delay Time | | -- | 25 | -- | nS |
| t _f | Turn-Off Fall Time | | -- | 12 | -- | nS |

Source-Drain Diode Characteristics

| | | | | | | |
|-----------------|--------------------|--|----|----|-----|---|
| V _{SD} | Forward on voltage | T _J =25°C, I _S =8A | -- | -- | 1.2 | V |
|-----------------|--------------------|--|----|----|-----|---|

Typical Operating Characteristics

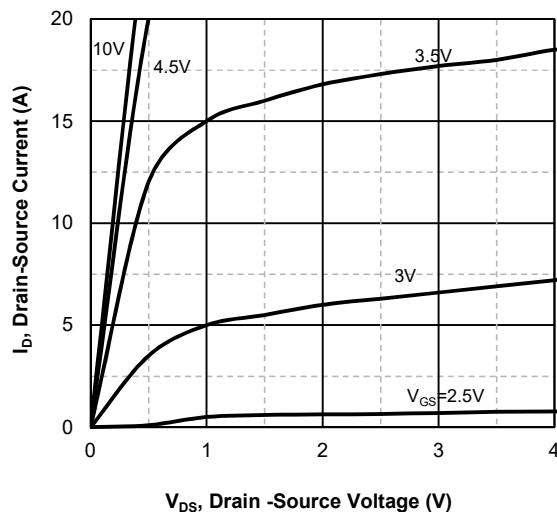


Fig1. Typical Output Characteristics

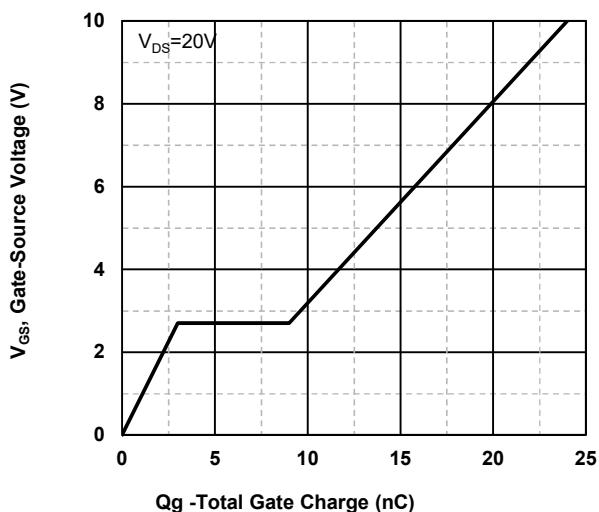


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

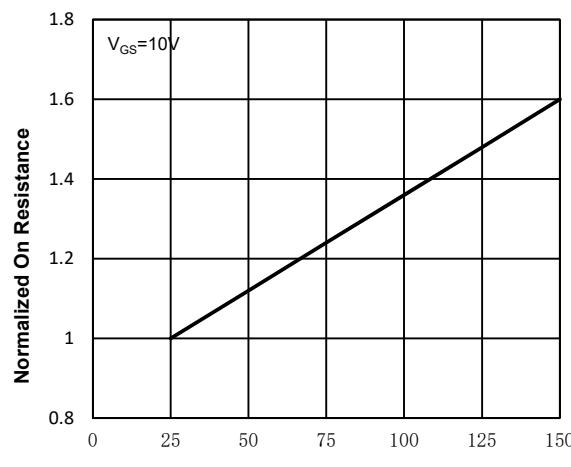


Fig3. Normalized On-Resistance Vs. Temperature

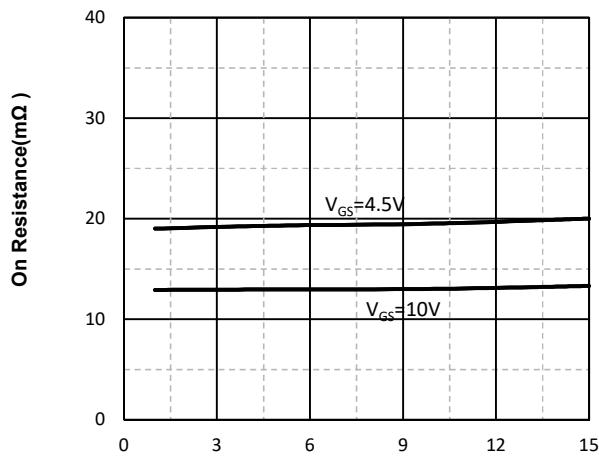


Fig4. On-Resistance Vs. Drain-Source Current

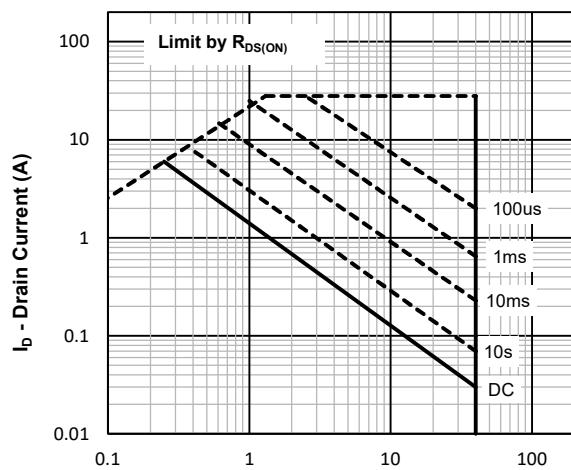


Fig5. Maximum Safe Operating Area

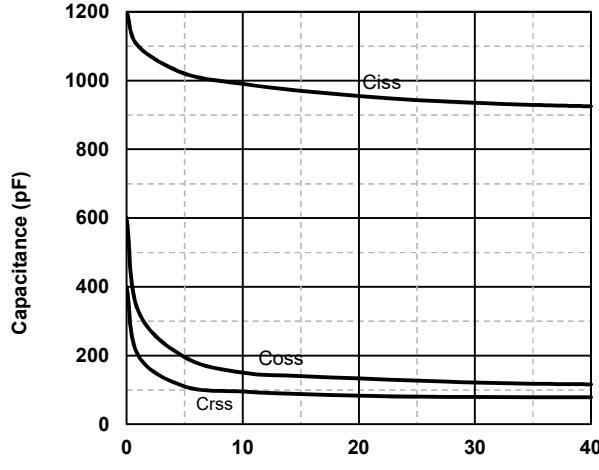
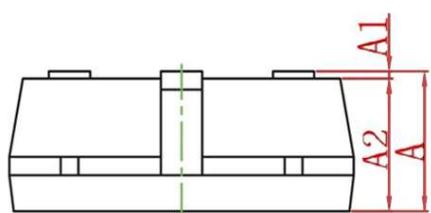
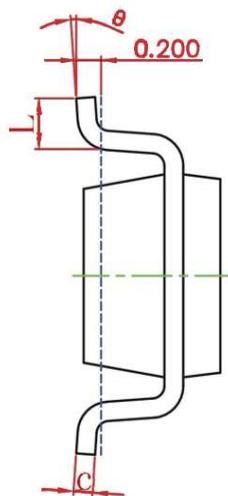
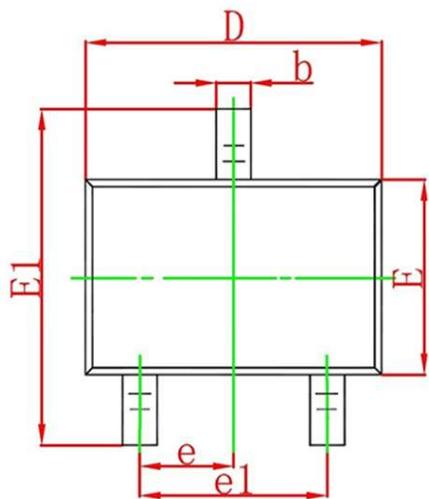


Fig6 Typical Capacitance Vs.Drain-Source Voltage

SOT-23-3L Package information



| Symbol | Dimensions in Millimeters(mm) | | Dimensions In Inches | |
|--------|-------------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.042 | 0.050 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.042 | 0.046 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.112 | 0.120 |
| E | 1.500 | 1.700 | 0.060 | 0.068 |
| E1 | 2.650 | 2.950 | 0.106 | 0.118 |
| e | 0.950TYP | | 0.037TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |